

Bias Resistor Transistors (BRT) NPN, 50 V, 100 mA

NSBCMXW Series

The series of digital transistors is designed to replace a single device and its external resistor bias network. The Bias Resistor Transistor contains a single transistor with a monolithic bias network consisting of two resistors: a series base resistor and a base–emitter resistor. The BRT eliminates these individual components by integrating them into a single device. The use of a BRT can reduce both system cost and board space. They are housed in the DFN1010–3 package offering superior thermal performance. The transistor is ideal for surface mount applications where board space and reliability are at a premium.

Features

- Built in Bias Resistors
- Complimentary PNP Types Available
- XDFNW3 Package Offers Low Seated Height 0.44 mm Max
- Wettable Flank Package for Optimal Automated Optical Inspection (AOI)
- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

Applications

- Digital Switching
- Controlling IC Input

MAXIMUM RATINGS (T_A = 25°C)

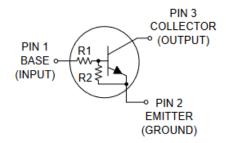
Rating	Symbol	Min	Max	Unit
Collector - Emitter Voltage	V_{CEO}		50	V
Collector - Base Voltage	V _{CBO}		50	V
Input Voltage NSBC114EMXWTBG NSBC124EMXWTBG NSBC144EMXWTBG NSBC143ZMXWTBG NSBC143XMXWTBG NSBC124XMXWTBG	VI	-10 -10 -10 -5 -7	+40 +40 +40 +30 +20 +40	>
Collector Current	I _C		100	mA
Electrostatic discharge (HBM)	ESD	Class 1B		

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

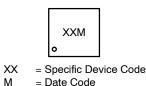
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PIN CONNECTIONS



MARKING DIAGRAM



ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Power Dissipation @ T _A = 25°C (Note 1)	P_{D}	450	mW
Thermal Resistance, Junction-to-Ambient (Note 1)	$R_{ heta JA}$	145	°C/W
Junction and Storage Temperature Range	T _J , T _{stg}	-65 to +150	°C

^{1.} Per JESD51-7 with standard PCB footprint and 2 oz. Cu.

ORDERING INFORMATION

Device	Device-Automotive*	R1	R2	Part Marking	Package [†]	Shipping			
NSBC114EMXWTBG	NSVBC114EMXWTBG	10	10	ЗW	XDFNW3 (Pb-Free)	3000 / Tape & Reel			
NSBC124EMXWTBG	NSVBC124EMXWTBG	22	22	3X		(Fb-Flee)	(PD-Fiee)	(1 5-1 166)	
NSBC144EMXWTBG	NSVBC144EMXWTBG	47	47	3Z					
NSBC143ZMXWTBG	NSVBC143ZMXWTBG	4.7	47	3Y					
NSBC143XMXWTBG	NSVBC143XMXWTBG	4.7	10	3V					
NSBC124XMXWTBG	NSVBC124XMXWTBG	22	47	ЗТ					

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*S and NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and

PPAP Capable.

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic		Symbol	Min - -	Typ _ _	Max 100 500	Unit nA nA
Collector-Base Cutoff Current (I _{CBO}					
Collector-Emitter Cutoff Current (V _{CE} = 50 V, I _B = 0)		I _{CEO}				
Emitter-Base Cutoff Current	NSBC114E	I _{EBO}	_	-	0.5	mA
$(V_{EB} = 6 \text{ V}, I_{C} = 0)$	NSBC124E		_	-	0.2	
	NSBC144E		_	-	0.1	
	NSBC143Z		_	-	0.2	
	NSBC124X		_	-	0.13	
	NSBC143X		_	_	0.5	1
DC Current Gain	NSBC114E	h _{FE}	35	_	-	
$(V_{CE} = 10.0 \text{ V}, I_{C} = 5 \text{ mA})$	NSBC124E		60	_	-	
	NSBC144E		80	_	-	
	NSBC143Z		80	_	-	
	NSBC143X		35	_	-	
	NSBC124X		80	_	-	
Collector-Emitter Saturation Vo	Itage (I _C = 10 mA, I _B = 0.3 mA)	V _{CE(sat)}	_	_	0.25	V
Input Voltage (off)	NSBC114E	V _{I(off)}	_	1.2	0.8	V
$(V_{CE} = 5.0 \text{ V}, I_{C} = 100 \mu\text{A})$ Input Voltage (off)	NSBC124E		_	1.2	0.8	
$(V_{CE} = 5.0 \text{ V}, I_{C} = 100 \mu\text{A})$	NSBC144E		_	1.2	0.8	
	NSBC143Z		_	0.6	0.5	
	NSBC124X		_	0.9	0.5	
	NSBC143X		_	0.9	0.3	
Input Voltage (on)	NSBC114E (V _{CE} = 0.3 V, I _C = 10 mA)	V _{I(on)}	2.5	1.8	-	V
	NSBC124E (V _{CE} = 0.3 V, I _C = 5 mA)		2.5	1.6	-	
	NSBC144E (V _{CE} = 0.3 V, I _C = 2 mA)		3	1.6	-	
	NSBC143Z (V _{CE} = 0.3 V, I _C = 5 mA)		1.3	0.9	-	
	NSBC143X (V _{CE} = 0.3 V, I _C = 20 mA)		2.5	2	-	
	NSBC124X (VCE = 0.3 V, IC = 2 mA)		2	12	-	1
Output Voltage (on) (V_{CC} = 5.0 V, V_B = 3.5 V, R_L = 1.0 k Ω)		V _{OL}	_	_	0.2	V
Output Voltage (off) (V _{CC} = 5.0	$V, V_B = 0.5 V, R_L = 1.0 k\Omega$	V _{OH}	4.9	_	-	V
Bias Resistor (R1)	NSBC114E	R1	7	10	13	kΩ
	NSBC124E		15.4	22	28.6	1
	NSBC144E	32.9	47	61.1		
	NSBC143Z		3.3	4.7	6.1	1
	NSBC143X		3.3	4.7	6.1	1
	NSBC124X		15.4	22	28.6	1

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic		Symbol	Min	Тур	Max	Unit	
Resistor Ratio	NSBC114E		R1/R2	0.8	1	1.2	
	NSBC124E			8.0	1	1.2	
	NSBC144E			8.0	1	1.2	
	NSBC143Z			0.08	0.1	0.12	
	NSBC143X			0.38	0.47	0.56	
	NSBC124X			0.38	0.47	0.56	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

TYPICAL CHARACTERISTICS (Ref. NSBC144E)

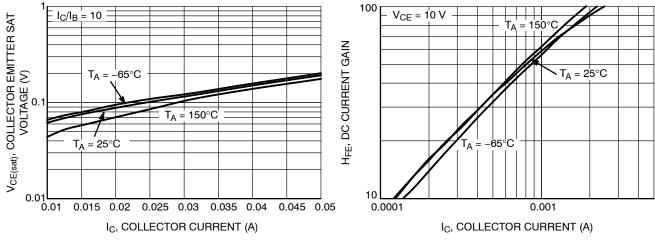


Figure 1. V_{CE(sat)} vs. I_C

Figure 2. DC Current Gain

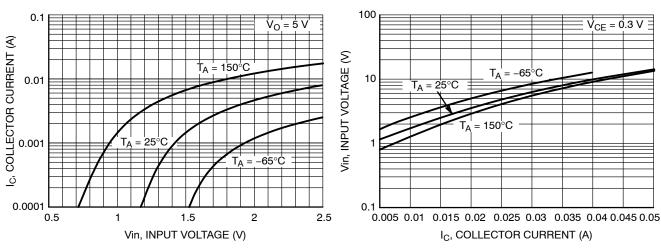


Figure 3. Output Current vs. Input Voltage

Figure 4. Input Voltage vs. Output Current

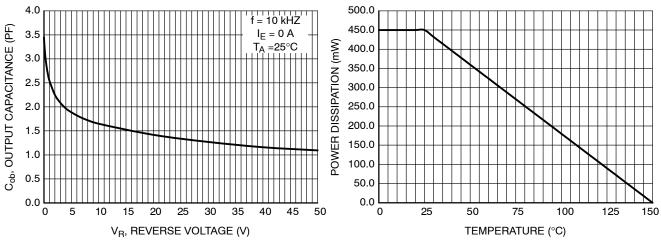


Figure 5. Output Capacitance

Figure 6. Derating Curve

TYPICAL CHARACTERISTICS

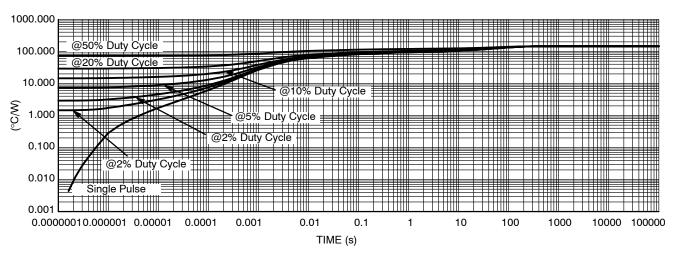
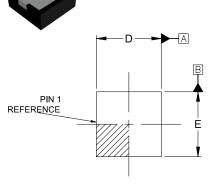


Figure 7. Transient Thermal Impedance from Junction-to-Ambient as a Function of Pulse Duration

PACKAGE DIMENSIONS

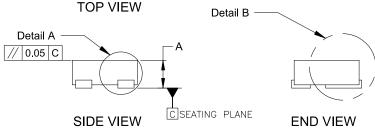
XDFNW3 1.00x1.00x0.38 0.65P CASE 521AC ISSUE B

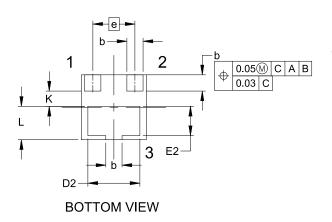


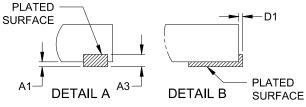
NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018.
- 2. CONTROLLING DIMENSION: MILLIMETERS

	MILLIMETERS				
DIM	MIN.	NOM.	MAX.		
Α	0.32	0.38	0.44		
A1	0.00		0.04		
А3	0.125 REF				
b	0.20	0.25	0.30		
D	0.90	1.00	1.10		
D1	0.00		0.04		
D2	0.75	0.80	0.85		
E	0.90	1.00	1.10		
E2	0.40	0.45	0.50		
е	0.65 BSC				
L	0.465	0.515	0.565		
K	0.23 REF				







0.68 0.68 2X 0.38 1.24 0.65 PITCH

GENERIC MARKING DIAGRAM*



XX = Specific Device Code M = Month Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

RECOMMENDED MOUNTING FOOTPRINT*

 For additional information on our Pb-Free strategy and soldering details, please download the ONSEMI Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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